Digital Transistors (BRT) R1 = 2.2 k Ω , R2 = ∞ k Ω

NPN Transistors with Monolithic Bias Resistor Network

This series of digital transistors is designed to replace a single device and its external resistor bias network. The Bias Resistor Transistor (BRT) contains a single transistor with a monolithic bias network consisting of two resistors; a series base resistor and a base–emitter resistor. The BRT eliminates these individual components by integrating them into a single device. The use of a BRT can reduce both system cost and board space.

Features

- Simplifies Circuit Design
- Reduces Board Space
- Reduces Component Count
- S Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q101 Qualified and PPAP Capable
- These Devices are Pb–Free, Halogen Free/BFR Free and are RoHS Compliant

MAXIMUM RATINGS ($T_A = 25^{\circ}C$)

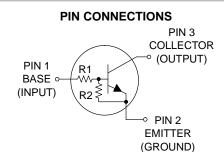
| Rating | Symbol | Max | Unit |
|--------------------------------|----------------------|-----|------|
| Collector-Base Voltage | V _{CBO} | 50 | Vdc |
| Collector–Emitter Voltage | V _{CEO} | 50 | Vdc |
| Collector Current – Continuous | ۱ _C | 100 | mAdc |
| Input Forward Voltage | V _{IN(fwd)} | 12 | Vdc |
| Input Reverse Voltage | V _{IN(rev)} | 6 | Vdc |

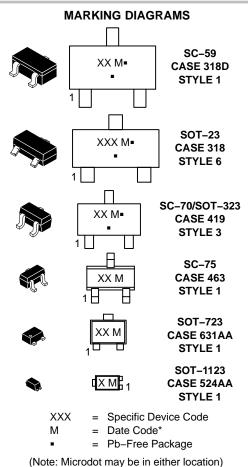
Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.



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*Date Code orientation may vary depending up-

on manufacturing location.

ORDERING INFORMATION

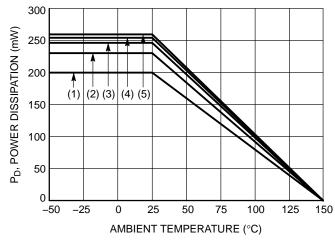
See detailed ordering, marking, and shipping information in the package dimensions section on page 2 of this data sheet.

Table 1. ORDERING INFORMATION

| Device | Part Marking | Package | Shipping [†] |
|------------------------------|--------------|----------------------------|-----------------------|
| MUN2238T1G | 6Q | SC-59 (Pb-Free) | 3000 / Tape & Reel |
| MMUN2238LT1G, SMMUN2238LTIG* | A8R | SOT-23 (Pb-Free) | 3000 / Tape & Reel |
| MUN5238T1G | AQ | SC-70/SOT-323 (Pb-Free) | 3000 / Tape & Reel |
| DTC123TET1G | 7R | SC-75 (Pb-Free) | 3000 / Tape & Reel |
| DTC123TM3T5G | 7C | SOT-732 (Pb-Free) | 8000 / Tape & Reel |
| NSBC123TF3T5G | Т | SOT-1123 (Pb-Free) | 8000 / Tape & Reel |

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

*S Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC–Q101 Qualified and PPAP Capable.



SC-75 and SC-70/SOT323; Minimum Pad
 SC-59; Minimum Pad
 SOT-23; Minimum Pad
 SOT-1123; 100 mm², 1 oz. copper trace
 SOT-723; Minimum Pad

Figure 1. Derating Curve

Table 2. THERMAL CHARACTERISTICS

| Characteristic | | Symbol | Max | Unit |
|---|--|-----------------------------------|--------------------------|-------------|
| THERMAL CHARACTERISTICS (SC-59) (MUN2238) | | | | |
| Total Device Dissipation $T_A = 25^{\circ}C$ Derate above 25°C | (Note 1) (Note 2) (Note 1) | P _D | 230 338 1.8 | mW mW/°C |
| Thermal Resistance, | (Note 2) (Note 1) | $R_{	heta JA}$ | 2.7 540 | °C/W |
| Junction to Ambient Thermal Resistance. | (Note 2) (Note 1) | $R_{	hetaJL}$ | 370 264 | °C/W |
| Junction to Lead | (Note 2) | | 287 | |
| Junction and Storage Temperature Range | | T _J , T _{stg} | -55 to +150 | °C |
| THERMAL CHARACTERISTICS (SOT-23) (MMUN2238L) | | | | |
| Total Device Dissipation $T_A = 25^{\circ}C$ Derate above $25^{\circ}C$ | (Note 1) (Note 2) (Note 1) | P _D | 246 400 2.0 | mW mW/°C |
| | (Note 2) | | 3.2 | |
| Thermal Resistance, Junction to Ambient | (Note 1) (Note 2) | R_{\thetaJA} | 508 311 | °C/W |
| Thermal Resistance, Junction to Lead | (Note 1) (Note 2) | $R_{	heta JL}$ | 174 208 | °C/W |
| Junction and Storage Temperature Range | | T _J , T _{stg} | -55 to +150 | °C |
| THERMAL CHARACTERISTICS (SC-70/SOT-323) (MUN5238) | | | | |
| Total Device Dissipation | | PD | | |
| $T_A = 25^{\circ}C$ Derate above $25^{\circ}C$ | (Note 1) (Note 2) (Note 1) (Note 2) | | 202 310 1.6 2.5 | mW mW/°C |
| Thermal Resistance, Junction to Ambient | (Note 1) (Note 2) | R_{\thetaJA} | 618 403 | °C/W |
| Thermal Resistance, Junction to Lead | (Note 1) (Note 2) | $R_{\theta JL}$ | 280 332 | °C/W |
| Junction and Storage Temperature Range | | T _J , T _{stg} | -55 to +150 | °C |
| THERMAL CHARACTERISTICS (SC-75) (DTC123TE) | • | | | |
| Total Device Dissipation $T_A = 25^{\circ}C$ | (Note 1) | PD | 200 | mW |
| Derate above 25°C | (Note 2) (Note 1) (Note 2) | | 300 1.6 2.4 | mW/°C |
| Thermal Resistance, Junction to Ambient | (Note 1) (Note 2) | R_{\thetaJA} | 600 400 | °C/W |
| Junction and Storage Temperature Range | | T _J , T _{stg} | -55 to +150 | °C |
| THERMAL CHARACTERISTICS (SOT-723) (DTC123TM3) | | | | |
| Total Device Dissipation $T_A = 25^{\circ}C$ | (Note 1) | PD | 260 | mW |
| Derate above 25°C | (Note 2) (Note 1) (Note 2) | | 600 2.0 4.8 | mW/∘C |
| Thermal Resistance, Junction to Ambient | (Note 1) (Note 2) | $R_{	hetaJA}$ | 480 205 | °C/W |
| Junction and Storage Temperature Range | | T _J , T _{stg} | -55 to +150 | °C |

FR-4 @ Minimum Pad.
 FR-4 @ 1.0 x 1.0 Inch Pad.
 FR-4 @ 100 mm², 1 oz. copper traces, still air.
 FR-4 @ 500 mm², 1 oz. copper traces, still air.

Table 2. THERMAL CHARACTERISTICS

| Characteristic | | Symbol | Max | Unit |
|--|--|-----------------------------------|--------------------------|-------------|
| THERMAL CHARACTERISTICS (SOT-1123) (NSBC123TF3) | | | | |
| Total Device Dissipation $T_A = 25^{\circ}C$ Derate above 25°C | (Note 3) (Note 4) (Note 3) (Note 4) | P _D | 254 297 2.0 2.4 | mW mW/°C |
| Thermal Resistance, Junction to Ambient | (Note 3) (Note 4) | $R_{	hetaJA}$ | 493 421 | °C/W |
| Thermal Resistance, Junction to Lead | (Note 3) | $R_{	ext{	heta}JL}$ | 193 | °C/W |
| Junction and Storage Temperature Range | | T _J , T _{stg} | -55 to +150 | °C |

1. FR-4 @ Minimum Pad.

2. FR-4 @ 1.0 x 1.0 Inch Pad.

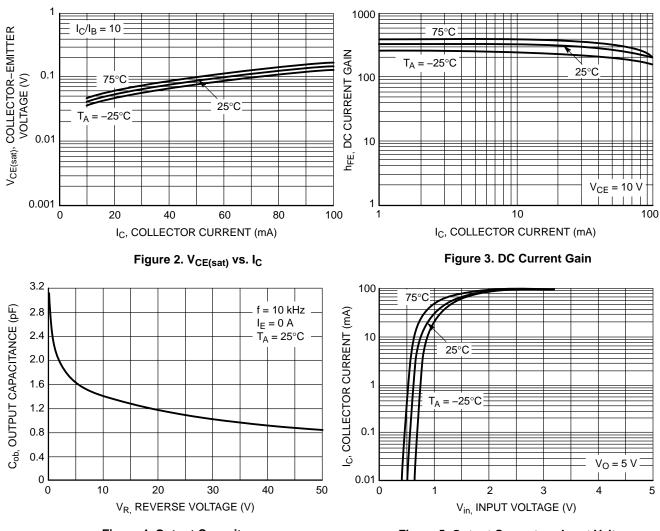
3. FR-4 @ 100 mm², 1 oz. copper traces, still air. 4. FR-4 @ 500 mm², 1 oz. copper traces, still air.

Table 3. ELECTRICAL CHARACTERISTICS (T_A = 25°C, unless otherwise noted)

| Characteristic | Symbol | Min | Тур | Max | Unit |
|--|--------------------------------|-----|-----|------|------|
| OFF CHARACTERISTICS | | | | | |
| Collector–Base Cutoff Current ($V_{CB} = 50 \text{ V}, I_E = 0$) | I _{CBO} | _ | _ | 100 | nAdc |
| Collector–Emitter Cutoff Current $(V_{CE} = 50 \text{ V}, I_B = 0)$ | I _{CEO} | _ | _ | 500 | nAdc |
| Emitter–Base Cutoff Current ($V_{EB} = 6.0 \text{ V}, I_C = 0$) | I _{EBO} | _ | _ | 4.0 | mAdc |
| Collector–Base Breakdown Voltage $(I_C = 10 \ \mu A, I_E = 0)$ | V _{(BR)CBO} | 50 | _ | - | Vdc |
| Collector–Emitter Breakdown Voltage (Note 5) $(I_C = 2.0 \text{ mA}, I_B = 0)$ | V _(BR) CEO | 50 | _ | - | Vdc |
| ON CHARACTERISTICS | | | | | |
| DC Current Gain (Note 5) ($I_C = 5.0 \text{ mA}, V_{CE} = 10 \text{ V}$) | h _{FE} | 160 | 350 | - | |
| Collector–Emitter Saturation Voltage (Note 5) $(I_C = 10 \text{ mA}, I_B = 1.0 \text{ mA})$ | V _{CE(sat)} | _ | _ | 0.25 | Vdc |
| Input Voltage (off) ($V_{CE} = 5.0 \text{ V}, I_C = 100 \mu\text{A}$) | V _{i(off)} | _ | 0.6 | 0.5 | Vdc |
| Input Voltage (on) ($V_{CE} = 0.3 \text{ V}, I_{C} = 10 \text{ mA}$) | V _{i(on)} | 1.1 | 0.8 | _ | Vdc |
| Output Voltage (on) (V_{CC} = 5.0 V, V_B = 2.5 V, R_L = 1.0 k Ω) | V _{OL} | _ | _ | 0.2 | Vdc |
| Output Voltage (off) $(V_{CC} = 5.0 \text{ V}, \text{ V}_{B} = 0.25 \text{ V}, \text{ R}_{L} = 1.0 \text{ k}\Omega)$ | V _{OH} | 4.9 | _ | _ | Vdc |
| Input Resistor | R1 | 1.5 | 2.2 | 2.9 | kΩ |
| Resistor Ratio | R ₁ /R ₂ | - | - | - | |

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

5. Pulsed Condition: Pulse Width = 300 msec, Duty Cycle $\leq 2\%$.



TYPICAL CHARACTERISTICS MUN2238, MMUN2238L, MUN5238, DTC123TE, DTC123TM3

Figure 4. Output Capacitance



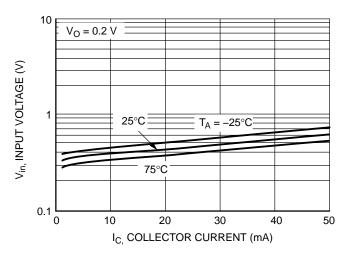
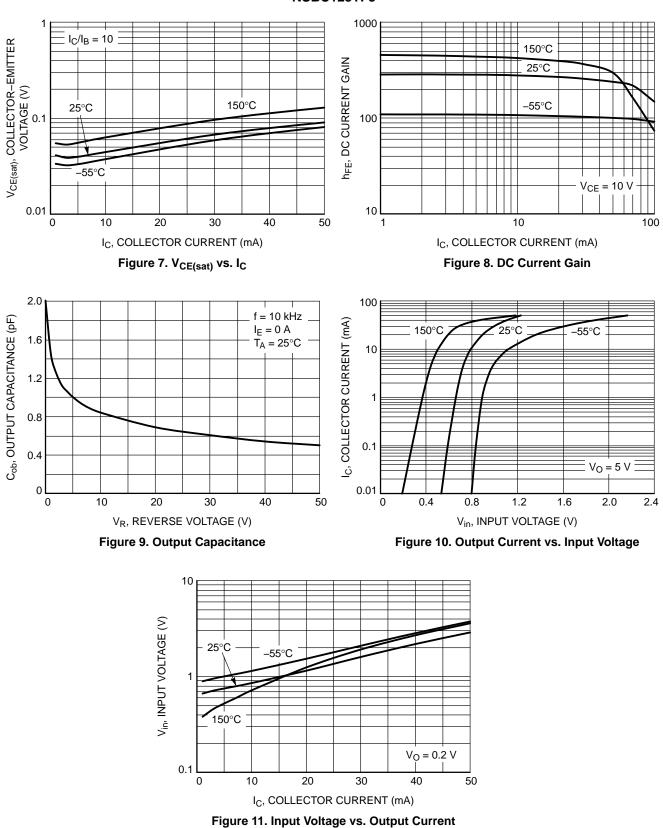


Figure 6. Input Voltage vs. Output Current



TYPICAL CHARACTERISTICS NSBC123TF3





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SCALE 2:1



SOLDERING FOOTPRINT*



*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

SC-59 CASE 318D-04 ISSUE H

DATE 28 JUN 2012

NOTES:

DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
 CONTROLLING DIMENSION: MILLIMETER.

| | MILLIMETERS | | | | INCHES | |
|-----|-------------|------|------|-------|--------|-------|
| DIM | MIN | NOM | MAX | MIN | NOM | MAX |
| Α | 1.00 | 1.15 | 1.30 | 0.039 | 0.045 | 0.051 |
| A1 | 0.01 | 0.06 | 0.10 | 0.001 | 0.002 | 0.004 |
| b | 0.35 | 0.43 | 0.50 | 0.014 | 0.017 | 0.020 |
| С | 0.09 | 0.14 | 0.18 | 0.003 | 0.005 | 0.007 |
| D | 2.70 | 2.90 | 3.10 | 0.106 | 0.114 | 0.122 |
| E | 1.30 | 1.50 | 1.70 | 0.051 | 0.059 | 0.067 |
| е | 1.70 | 1.90 | 2.10 | 0.067 | 0.075 | 0.083 |
| L | 0.20 | 0.40 | 0.60 | 0.008 | 0.016 | 0.024 |
| HE | 2.50 | 2.80 | 3.00 | 0.099 | 0.110 | 0.118 |

GENERIC **MARKING DIAGRAM**



= Specific Device Code XXX Μ = Date Code

= Pb-Free Package*

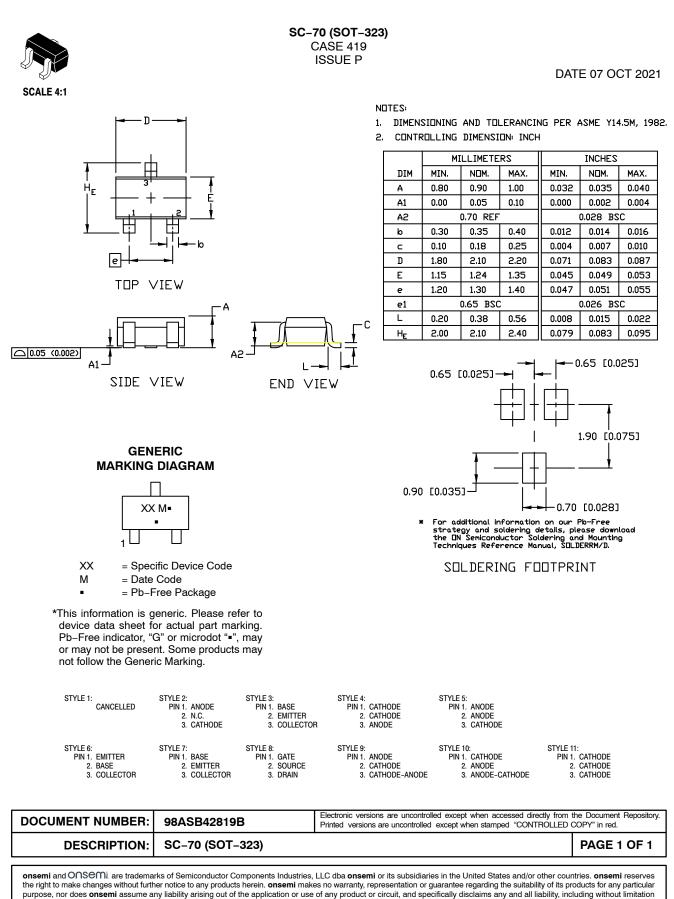
(*Note: Microdot may be in either location)

*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "•", may or may not be present.

| STYLE 1: | STYLE 2: | STYLE 3: |
|----------------|----------------|------------------|
| PIN 1. BASE | PIN 1. ANODE | PIN 1. ANODE |
| 2. EMITTER | 2. N.C. | 2. ANODE |
| 3. COLLECTOR | 3. CATHODE | 3. CATHODE |
| Style 4: | Style 5: | STYLE 6: |
| Pin 1. Cathode | Pin 1. Cathode | PIN 1. ANODE |
| 2. N.C. | 2. Cathode | 2. CATHODE |
| 3. Anode | 3. Anode | 3. ANODE/CATHODE |

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1.000

0.039

SCALE 10:1

mm

inches

0.508

0.020

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SCALE 8:1



SOT-1123 CASE 524AA ISSUE C





SOLDERING FOOTPRINT*



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| STYLE 1: | STYLE 2: | STYLE 3: | STYLE 4: | STYLE 5: |
|--------------|--------------|--------------|----------------|-------------|
| PIN 1. BASE | PIN 1. ANODE | PIN 1. ANODE | PIN 1. CATHODE | PIN 1. GATE |
| 2. EMITTER | 2. N/C | 2. ANODE | 2. CATHODE | 2. SOURCE |
| 3. COLLECTOR | 3. CATHODE | 3. CATHODE | 3. ANODE | 3. DRAIN |
| | | | | |

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|---------------------------------|---|--|------------------------|
| DESCRIPTION: | SOT-1123, 3-LEAD, 1.0X0 | SOT-1123, 3-LEAD, 1.0X0.6X0.37, 0.35P PA | |
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DATE 29 NOV 2011

- NOTES:
- NOTES: 1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994. 2. CONTROLLING DIMENSION: MILLIMETERS. 3. MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH. MINIMUM LEAD THICKNESS IS THE
- MINIMUM THICKNESS OF BASE MATERIAL. DIMENSIONS D AND E DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR GATE BURRS. 4.

| | MILLIM | MILLIMETERS | | |
|-----|-----------|-------------|--|--|
| DIM | MIN | MAX | | |
| Α | 0.34 | 0.40 | | |
| b | 0.15 | 0.28 | | |
| b1 | 0.10 | 0.20 | | |
| С | 0.07 | 0.17 | | |
| D | 0.75 | 0.85 | | |
| Е | 0.55 | 0.65 | | |
| е | 0.35 | 0.40 | | |
| HE | 0.95 | 1.05 | | |
| L | 0.185 REF | | | |
| L2 | 0.05 | 0.15 | | |

GENERIC **MARKING DIAGRAM***

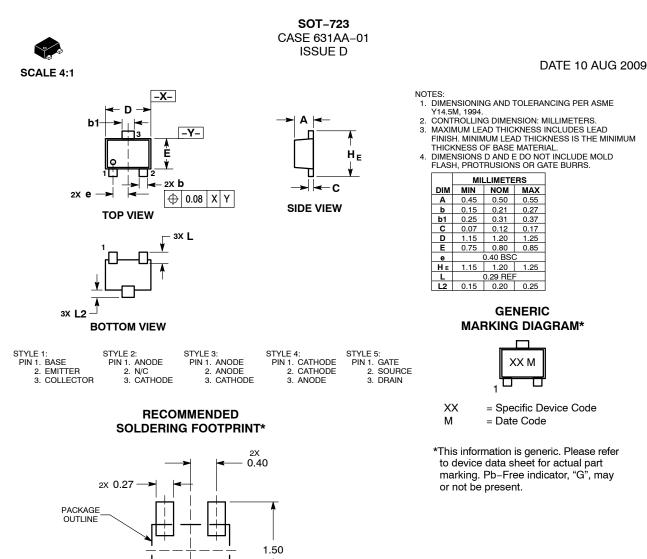
= Specific Device Code Х Μ = Date Code

*This information is generic. Please refer to device data sheet for actual part marking.

Pb-Free indicator, "G" or microdot " .", may or may not be present.

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3X 0.52 - - 0.36 DIMENSIONS: MILLIMETERS

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